

Transistors

4V Drive Nch MOS FET

RHP030N03

●Structure

Silicon N-channel MOS FET

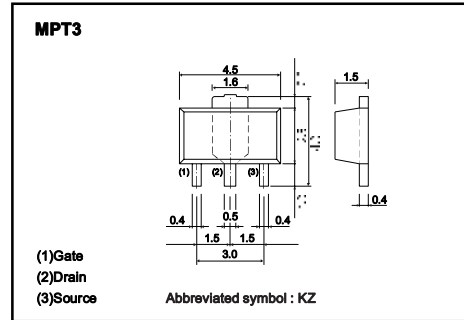
●Features

- 1) Low On-resistance.
- 2) 4V drive.

●Applications

Switching

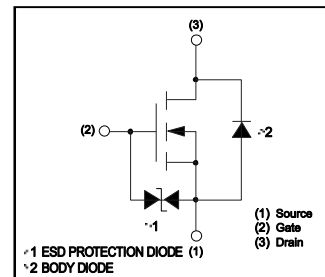
●External dimensions (Unit : mm)



●Packaging specifications

Type	Package	Taping
	Code	T100
	Basic ordering unit (pieces)	1000
RHP030N03		○

●Inner circuit

●Absolute maximum ratings ($T_a=25^{\circ}\text{C}$)

Parameter	Symbol	Limits	Unit	
Drain-source voltage	V_{DS}	30	V	
Gate-source voltage	V_{GS}	± 20	V	
Drain current	Continuous	I_D	3	A
	Pulsed	I_{DP} *1	10	A
Reverse drain current	Continuous	I_{DR}	3	A
	Pulsed	I_{DRP} *1	10	A
Total power dissipation	P_D	500	mW	
		2 *2	W	
Channel temperature	T_{ch}	150	$^{\circ}\text{C}$	
Range of storage temperature	T_{stg}	-55 to +150	$^{\circ}\text{C}$	

*1 $P_w \leq 10\mu\text{s}$, Duty cycle $\leq 1\%$

*2 When mounted on a 40x40x0.7mm ceramic board

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th(ch-a)}$	250	$^{\circ}\text{C/W}$
		62.5 *	$^{\circ}\text{C/W}$

* When mounted on a 40x40x0.7mm ceramic board

Transistors

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	–	–	±10	μA	V _{GS} =±20V, V _{DS} =0V
Drain-source breakdown voltage	V _{(BR)DSS}	30	–	–	V	I _D = 1mA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}	–	–	1	μA	V _{DS} = 30V, V _{GS} =0V
Gate threshold voltage	V _{GS(th)}	1.0	–	2.5	V	V _{DS} = 10V, I _D = 1mA
Static drain-source on-state resistance	R _{DS(on)}	–	90	120	mΩ	I _D = 3A, V _{GS} = 10V
		–	160	210	mΩ	I _D = 3A, V _{GS} = 4V
Forward transfer admittance	Y _{fs}	2.0	–	–	S	V _{DS} = 10V, I _D = 3A
Input capacitance	C _{iss}	–	160	–	pF	V _{DS} = 10V
Output capacitance	C _{oss}	–	90	–	pF	V _{GS} =0V
Reverse transfer capacitance	C _{rss}	–	27	–	pF	f=1MHz
Turn-on delay time	t _{d(on)}	–	7	–	ns	V _{DD} = 15V
Rise time	t _r	–	11	–	ns	I _D = 1.5A
Turn-off delay time	t _{d(off)}	–	15	–	ns	V _{GS} = 10V
Fall time	t _f	–	4.5	–	ns	R _L =10Ω R _G =10Ω
Total gate charge	Q _g	–	6.5	–	nC	V _{DD} = 15V
Gate-source charge	Q _{gs}	–	1.0	–	nC	V _{GS} = 10V
Gate-drain charge	Q _{gd}	–	1.5	–	nC	I _D = 3A

* Pulsed

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